

This article was downloaded by:

On: 29 January 2011

Access details: *Access Details: Free Access*

Publisher *Taylor & Francis*

Informa Ltd Registered in England and Wales Registered Number: 1072954 Registered office: Mortimer House, 37-41 Mortimer Street, London W1T 3JH, UK



Phosphorus, Sulfur, and Silicon and the Related Elements

Publication details, including instructions for authors and subscription information:

<http://www.informaworld.com/smpp/title~content=t713618290>

Editorial board page for “Phosphorus, Sulfur, and Silicon and the Related Elements”, Volume 86, Number 1-4

To cite this Article (1994) 'Editorial board page for “Phosphorus, Sulfur, and Silicon and the Related Elements”, Volume 86, Number 1-4', *Phosphorus, Sulfur, and Silicon and the Related Elements*, 86: 1, a

To link to this Article: DOI: 10.1080/10426509408015254

URL: <http://dx.doi.org/10.1080/10426509408015254>

PLEASE SCROLL DOWN FOR ARTICLE

Full terms and conditions of use: <http://www.informaworld.com/terms-and-conditions-of-access.pdf>

This article may be used for research, teaching and private study purposes. Any substantial or systematic reproduction, re-distribution, re-selling, loan or sub-licensing, systematic supply or distribution in any form to anyone is expressly forbidden.

The publisher does not give any warranty express or implied or make any representation that the contents will be complete or accurate or up to date. The accuracy of any instructions, formulae and drug doses should be independently verified with primary sources. The publisher shall not be liable for any loss, actions, claims, proceedings, demand or costs or damages whatsoever or howsoever caused arising directly or indirectly in connection with or arising out of the use of this material.

Phosphorus, Sulfur, and Silicon and the Related Elements

Editor in Chief: **R. R. Holmes**

Department of Chemistry, University of Massachusetts, Amherst, Massachusetts 01003 U.S.A.

European Editor: **L. Maier**

R-1059, 6.08, CIBA-GEIGY AG. CH-4002, Basel, Switzerland

Associate Editors

Editor Emeritus

W. Walter

*University of Hamburg
Institut für Organische Chemie
Martin-Luther-King-Platz 6
D-2000 Hamburg 13, Germany*

J. G. Verkade

*Department of Chemistry
Iowa State University
Ames, Iowa 50010,
U.S.A.*

L. Horner

Mainz, Germany

(For Communications and Reviews)

Editorial Board

R. P. Arshinova
*Russian Academy of
Sciences
Kazan, Russia*

K. D. Berlin
*Oklahoma State
University, Stillwater*

E. Block
*State University of
New York at Albany*

H. Bock
*The University
Frankfurt, Germany*

R. Burgada
*Université P. et M. Curie
Paris, France*

J. Y. Corey
*University of
Missouri, St. Louis*

R. Corriu
*University of Science
and Technology of
Languedoc, France*

S. Cremer
*Marquette University
Milwaukee, Wisconsin*

F. A. Davis
*Drexel University
Philadelphia,
Pennsylvania*

S. A. Evans, Jr.
*University of
North Carolina at
Chapel Hill*

L. Field
*Vanderbilt University
Nashville, Tennessee*

E. Fluck
*Gmelin Institute
Frankfurt, Germany*

P. Gaspar
*Washington
University
St. Louis, Missouri*

C. D. Hall
*King's College
London, UK*

S. Husebye
*University of Bergen
Norway*

N. Inamoto
*University of Tokyo
Japan*

K. Jurkschat
*Martin-Luther
University,
Halle, Germany*

J. F. King
*University of
Western Ontario
Canada*

O. I. Kolodiaznyi
*Academy of Sciences
of the Ukrainian SSR,
Kiev, Ukraine*

S. S. Krishnamurthy
*Indian Institute of
Science,
Bangalore, India*

J. P. Majoral
*Université Paul
Sabatier
Toulouse, France*

S. Masson
*Université de Caen
France*

T. A. Mastryukova
*Russian Academy of
Sciences
Moscow, Russia*

F. Mathey
*Ecole Polytechnique
Palaiseau, France*

M. Mikolajczyk
*Polish Academy of
Sciences
Lodz, Poland*

G. Modena
*The University
Padua, Italy*

J. F. Nixon
*University of Sussex
Brighton, UK*

E. E. Nifant'ev
*V. I. Lenin State
Pedag. Inst.
Moscow, Russia*

S. Oae
*Institute of Heteroatom
Chemistry
Osaka, Japan*

L. D. Quin
*University of
Massachusetts
Amherst*

H. Roesky
*The University
Göttingen, Germany*

H. Sakurai
*Tohoku University
Sendai, Japan*

H. Schmidbaur
*Technical University
Munich, Germany*

A. Schmidpeter
*The University
Munich, Germany*

M. Schmidt
*The University
Würzburg, Germany*

R. Schmutzler
*The University
Braunschweig,
Germany*

R. A. Shaw
*Birkbeck College
London, UK*

R. Steudel
*Technical University of
Berlin, Germany*

B. S. Thyagarajan
*The University of
Texas at San Antonio*

J. C. Van de Grampel
*University of
Groningen
The Netherlands*

M. Veith
*Universität des
Saarlandes, Germany*

R. West
*University of
Wisconsin, Madison*

P. Wisian-Neilson
*Southern Methodist
University
Dallas, Texas*

B. Wladislaw
*University of São
Paulo, Brazil*

R. Wolf
*Université Paul
Sabatier
Toulouse, France*

C. Yuan
*Shanghai Institute of
Organic Chemistry
PRC*

H. Zimmer
*University of
Cincinnati, Ohio*

R. A. Zingaro
*Texas A&M
University
College Station*

B. Zwanenburg
*University of
Nijmegen
The Netherlands*

Aims and Scope

Phosphorus, Sulfur, and Silicon and the Related Elements welcomes submissions involving the organic, inorganic, and biochemistry of phosphorus (including arsenic, antimony, and bismuth), sulfur (including selenium and tellurium), and silicon (including germanium and tin). In addition to research describing new chemistry of a particular element, especially welcome are presentations emphasizing relationships between elements and families of elements: for example, research comparing synthetic, mechanistic, or structural features providing new insight leading to a more rapid advance of science in these areas.

Original articles, communications, and selected reviews of broad interest will be considered for publication. Manuscripts may include illustrative material in color if this will enhance the presentation. There are no page charges and 25 free reprints will be supplied to the principal author. Regular papers may be sent to R. R. Holmes in Amherst or to L. Maier in Basel. Communications and reviews should be sent to W. Walter in Hamburg or J. G. Verkade in Ames.

Notes for contributors, including information on communications and reviews, can be found at the back of the journal.

General Information

Please see the inside back cover for information on subscription rates, photocopy license, and article reprints.

© 1994. Published by Gordon and Breach Science Publishers SA, a member of The Gordon and Breach Publishing Group. All rights reserved.

Except as permitted under national laws or under the Photocopy License described below, no part of this publication may be reproduced or transmitted in any form or by any means, electronic, mechanical, photocopying or otherwise, or stored in a retrieval system of any nature, without the advance written permission of the Publisher.

Distributed by International Publishers Distributor.

Printed in the United States of America.

JANUARY 1994